

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- * 150 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

MAXIMUM KATINGO			
Characteristic	Symbol	S20C120	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	120	V
RMS Reverse Voltage	$V_{R(RMS)}$	84	V
Average Rectifier Forward Current $$ (per diode) Total Device (Rated V_R), T_C =100	$I_{F(AV)}$	10 20	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	200	A
Operating and Storage Junction Temperature Range	T_J , T_stg	-65 to +150	

THERMAL RESISTANCES

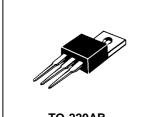
Typical Thermal Resistance junction to case	R _{θ j-c}	3.5	/w
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ELECTRIAL CHARACTERISTICS

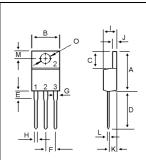
Characteristic	Symbol	S20C120	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25$) ($I_F = 10 \text{ Amp } T_C = 125$)	VF	0.85 0.78	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I _R	0.2 20	mA

SCHOTTKY BARRIER RECTIFIERS

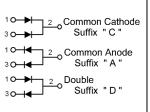
20 AMPERES 120 VOLTS

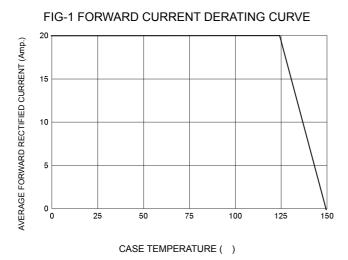


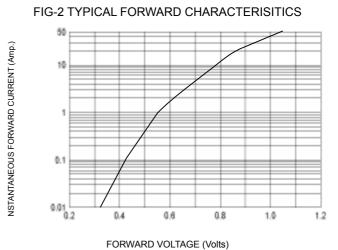
TO-220AB

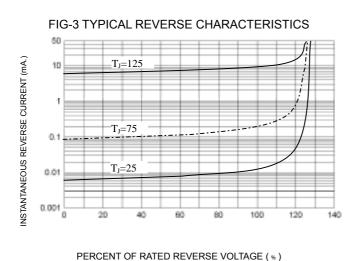


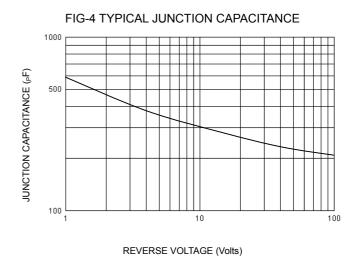
DIM	MILLIMETERS	
DIM	MIN	MAX
Α	14.68	15.32
В	9.78	10.42
С	5.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
Н	0.72	0.96
- 1	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
0	3.70	3.90

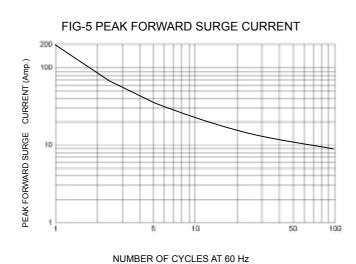














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